## NCE N-Channel Enhancement Mode Power MOSFET

### **Description**

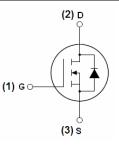
The NCE0260T uses advanced trench technology and design to provide excellent RDS(ON) with low gate charge. It can be used in a wide variety of applications.

#### **General Features**

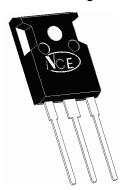
- $V_{DS}$  =200V, $I_{D}$  =60A  $R_{DS(ON)}$  <32m $\Omega$  @  $V_{GS}$ =10V
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E<sub>AS</sub>
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

### **Application**

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply



Schematic diagram



TO-247 top view

100% UIS TESTED! 100% ΔVds TESTED!

### **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE0260T	NCE0260T	TO-247	-	-	-

### Absolute Maximum Ratings (T<sub>c</sub>=25°Cunless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	V <sub>DS</sub>	200	V	
Gate-Source Voltage	V <sub>GS</sub>	±20	V	
Drain Current-Continuous	I <sub>D</sub>	60	Α	
Drain Current-Continuous(T <sub>C</sub> =100 °C)	I <sub>D</sub> (100℃)	42	Α	
Pulsed Drain Current	I <sub>DM</sub>	280	Α	
Maximum Power Dissipation	P <sub>D</sub>	300	W	
Derating factor		2.0	W/℃	
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	225	mJ	
Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 175	$^{\circ}$ C	

#### **Thermal Characteristic**

Thermal Resistance, Junction-to-Case (Note 2)	R <sub>eJC</sub>	0.5	°C/W

# **NCE0260T**

Electrical Characteristics (T<sub>C</sub>=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	<u>.</u>					
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	200	220	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =200V,V <sub>GS</sub> =0V	V <sub>DS</sub> =200V,V <sub>GS</sub> =0V -		1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)	<u>.</u>					
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	2	3.2	4	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =20A	-	24	32	mΩ
Forward Transconductance	<b>g</b> Fs	V <sub>DS</sub> =5V,I <sub>D</sub> =30A	40	-	-	S
Dynamic Characteristics (Note4)	<u>.</u>					
Input Capacitance	C <sub>lss</sub>	\/ -50\/\/ -0\/	-	6200	-	PF
Output Capacitance	Coss	$V_{DS}$ =50V, $V_{GS}$ =0V, F=1.0MHz	-	950	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.UIVIDZ	-	460	-	PF
Switching Characteristics (Note 4)	<u>.</u>					
Turn-on Delay Time	t <sub>d(on)</sub>		-	33	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =100V, $R_L$ =15 $\Omega$	-	20	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10V, $R_{G}$ =2.5 $\Omega$	-	21	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	31	-	nS
Total Gate Charge	Qg	\/ -400\/   -204	-	130		nC
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ =100V, $I_{D}$ =30A, $V_{GS}$ =10V	-	36		nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> -10V	-	46		nC
Drain-Source Diode Characteristics	<u>.</u>					
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =30A	-		1.2	V
Diode Forward Current (Note 2)	Is		-	-	60	Α
Reverse Recovery Time	t <sub>rr</sub>	TJ = 25°C, IF = 30A	-	42		nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs <sup>(Note3)</sup>	-	66		nC
Forward Turn-On Time	t <sub>on</sub>	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				
		*				

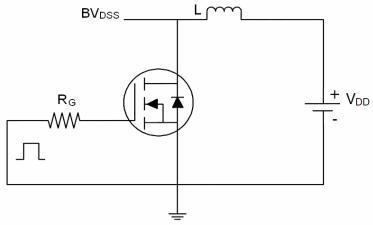
# Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width  $\leq$  300 $\mu$ s, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production
- 5.  $E_{AS}$  condition: j=25  $^{\circ}\!\mathrm{C}$  ,V  $_{DD}$  =50 V ,V  $_{G}$  =10 V ,L=0.5 mH ,Rg=25  $\Omega$

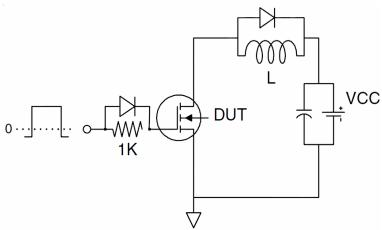
# NCE0260T

# **Test Circuit**

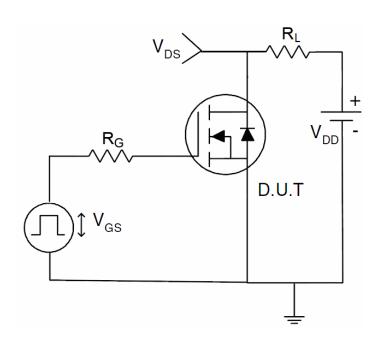
# 1) E<sub>AS</sub> test Circuits



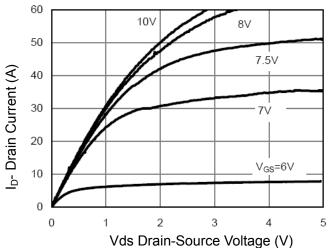
# 2) Gate charge test Circuit



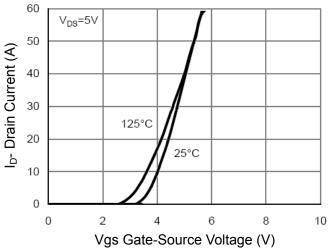
# 3) Switch Time Test Circuit



# Typical Electrical and Thermal Characteristics (Curves)



**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 

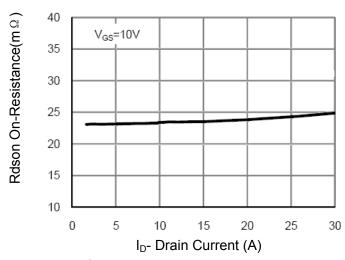
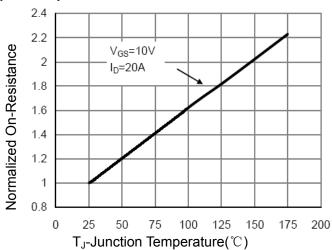


Figure 3 Rdson- Drain Current



**Figure 4 Rdson-Junction Temperature** 

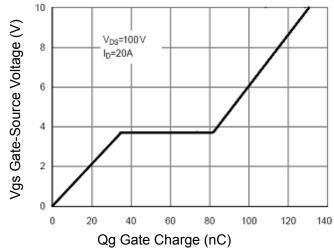


Figure 5 Gate Charge

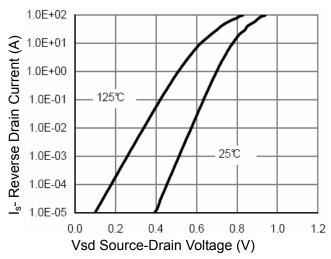


Figure 6 Source- Drain Diode Forward



**Pb Free Product** 

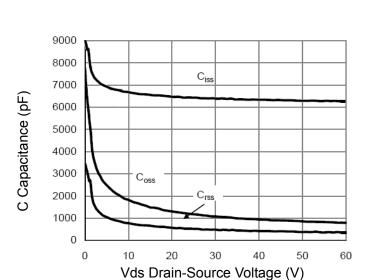


Figure 7 Capacitance vs Vds

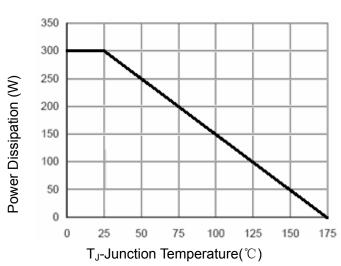


Figure 9 Power De-rating

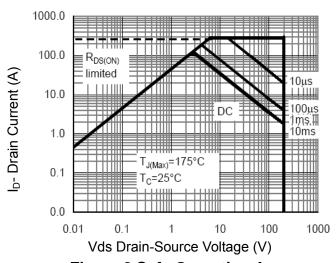


Figure 8 Safe Operation Area

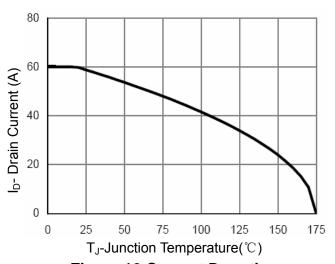
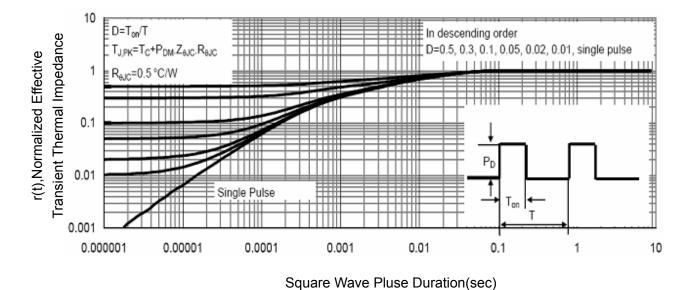


Figure 10 Current De-rating

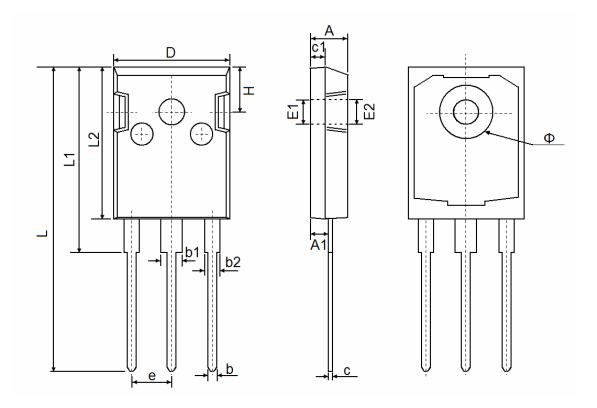


**Figure 11 Normalized Maximum Transient Thermal Impedance** 

**Pb Free Product** 



# **TO-247 Package Information**



Cumbal	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
А	4.850	5.150	0.191	0.200	
A1	2.200	2.600	0.087	0.102	
b	1.000	1.400	0.039	0.055	
b1	2.800	3.200	0.110	0.126	
b2	1.800	2.200	0.071	0.087	
С	0.500	0.700	0.020	0.028	
c1	1.900	2.100	0.075	0.083	
D	15.450	15.750	0.608	0.620	
E1	3.50	0 REF	0.138 REF		
E2	3.600 REF		0.142 REF		
L	40.900	41.300	1.610	1.626	
L1	24.800	25.100	0.976	0.988	
L2	20.300	20.600	0.799	0.811	
Φ	7.100	7.300	0.280	0.287	
е	5.450 TYP		0.215 TYP		
Н	5.98	0 REF	0.235 REF		



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NCE0260T

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